

**8 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY**
**Product Summary**

|                             |                             |                              |
|-----------------------------|-----------------------------|------------------------------|
| <b>V<sub>BR</sub> (Min)</b> | <b>I<sub>PP</sub> (Max)</b> | <b>C<sub>I/O</sub> (Typ)</b> |
| 5.5V                        | 5                           | 0.55pF                       |

**Description**

The D3V3F8U9LP3810 is a high-performance device suitable for protecting four high speed I/Os. These devices are assembled in U-DFN3810-9 (Type B) package and have high ESD surge capability, low ESD clamping voltage and ultra-low capacitance.

**Applications**

Typically used at high-speed ports such as USB 3.0, USB 3.1, Serial ATA, Display port.

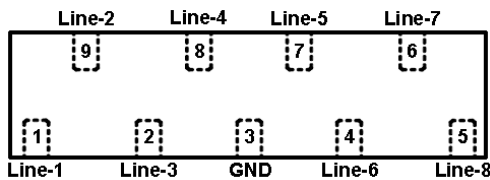
**Features**

- Clamping Voltage: 5V at 16A TLP
- IEC 61000-4-2 (ESD): Air — ±12kV, Contact — ±12kV
- IEC 61000-4-5 (Lightning): 5A (8/20µs)
- 8 Channels of ESD Protection
- Ultra-Low Channel Input Capacitance of 0.55pF Typical
- TLP Dynamic Resistance: 0.25Ω
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

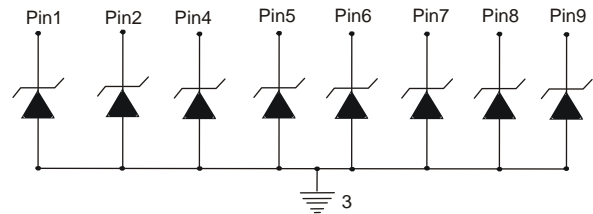
**Mechanical Data**

- Case: U-DFN3810-9 (Type B)
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Schematic
- Terminals: Finish – NiPdAu, Solderable per MIL-STD-202, Method 208 <sup>(e4)</sup>
- Weight: 0.005 grams (Approximate)

U-DFN3810-9 (Type B)



Pin Description (Top View)



Device Schematic

**Ordering Information** (Note 4)

| Part Number      | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity          |
|------------------|------------|---------|--------------------|-----------------|-------------------|
| D3V3F8U9LP3810-7 | Standard   | MW5     | 7                  | 8               | 3,000/Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

**Marking Information**

U-DFN3810-9 (Type B)



MW5 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year (ex: E = 2017)  
 M = Month (ex: 9 = September)

## Date Code Key

| Year | 2016 | 2017 | 2018 | 2019 | 2020 | 2021 |
|------|------|------|------|------|------|------|
| Code | D    | E    | F    | G    | H    | I    |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code  | 1   | 2   | 3   | 4   | 5   | 6   | 7   | 8   | 9   | O   | N   | D   |

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                        | Symbol                   | Value       | Unit | Conditions                      |
|-------------------------------------------------------|--------------------------|-------------|------|---------------------------------|
| Peak Pulse Current, per IEC 61000-4-5                 | I <sub>PP</sub>          | 5           | A    | I/O to V <sub>SS</sub> , 8/20μs |
| Peak Pulse Power, per IEC 61000-4-5                   | P <sub>PP</sub>          | 32          | W    | I/O to V <sub>SS</sub> , 8/20μs |
| ESD Protection – Contact Discharge, per IEC 61000-4-2 | V <sub>ESD_CONTACT</sub> | ±12         | kV   | I/O to V <sub>SS</sub>          |
| ESD Protection – Air Discharge, per IEC 61000-4-2     | V <sub>ESD_AIR</sub>     | ±12         | kV   | I/O to V <sub>SS</sub>          |
| Operating Temperature                                 | T <sub>OP</sub>          | -55 to +85  | °C   | —                               |
| Storage Temperature                                   | T <sub>STG</sub>         | -55 to +150 | °C   | —                               |

**Thermal Characteristics**

| Characteristic                                           | Symbol           | Value | Unit |
|----------------------------------------------------------|------------------|-------|------|
| Power Dissipation Typical (Note 5)                       | P <sub>D</sub>   | 350   | mW   |
| Thermal Resistance, Junction to Ambient Typical (Note 5) | R <sub>θJA</sub> | 360   | °C/W |

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic             | Symbol             | Min  | Typ   | Max | Unit | Test Conditions                                       |
|----------------------------|--------------------|------|-------|-----|------|-------------------------------------------------------|
| Reverse Working Voltage    | V <sub>RWM</sub>   | —    | —     | 3.3 | V    | I <sub>R</sub> =1mA, I/O to V <sub>SS</sub>           |
| Reverse Current            | I <sub>R</sub>     | —    | —     | 1.0 | μA   | V <sub>R</sub> = 3.3V, I/O to V <sub>SS</sub>         |
| Reverse Breakdown Voltage  | V <sub>BR</sub>    | 5.5  | 7.0   | —   | V    | I <sub>R</sub> = 1mA, I/O to V <sub>SS</sub>          |
| Forward Clamping Voltage   | V <sub>F</sub>     | -1.0 | -0.85 | —   | V    | I <sub>F</sub> = -15mA, I/O to V <sub>SS</sub>        |
| Holding Reverse Voltage    | V <sub>HOLD</sub>  | —    | 1.19  | —   | V    | I/O to V <sub>SS</sub>                                |
| Holding Reverse Current    | I <sub>HOLD</sub>  | —    | 90    | —   | mA   | I/O to V <sub>SS</sub>                                |
| Clamping Voltage (Note 6)  | V <sub>C</sub>     | —    | 5     | —   | V    | TLP, 16A, tp = 100ns, I/O to V <sub>SS</sub>          |
| Clamping Voltage (Note 6)  | V <sub>C</sub>     | —    | 5     | —   | V    | TLP, -16A, tp = 100ns, I/O to V <sub>SS</sub>         |
| Dynamic Reverse Resistance | R <sub>DIF-R</sub> | —    | 0.25  | —   | Ω    | TLP, 10A, tp = 100ns, I/O to V <sub>SS</sub>          |
| Dynamic Forward Resistance | R <sub>DIF-F</sub> | —    | 0.2   | —   | Ω    | TLP, 10A, tp = 100ns, V <sub>SS</sub> to I/O          |
| Channel Input Capacitance  | C <sub>I/O</sub>   | —    | 0.55  | —   | pF   | V <sub>I/O</sub> = 0V, V <sub>SS</sub> = 0V, f = 1MHz |

- Notes:
- Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at <http://www.diodes.com/package-outlines.html>.
  - Clamping voltage value is based on a TLP model. TLP conditions: Z<sub>0</sub>=50Ω, tp = 100ns, averaging window; t<sub>1</sub>=70ns to t<sub>2</sub>=90ns.

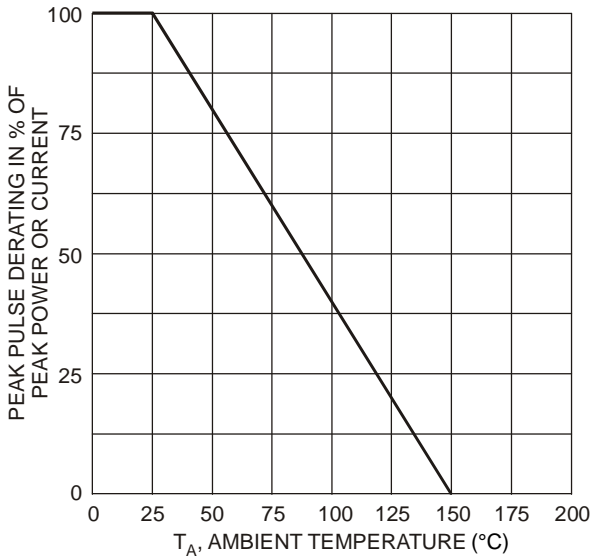


Figure 1 Pulse Derating Curve

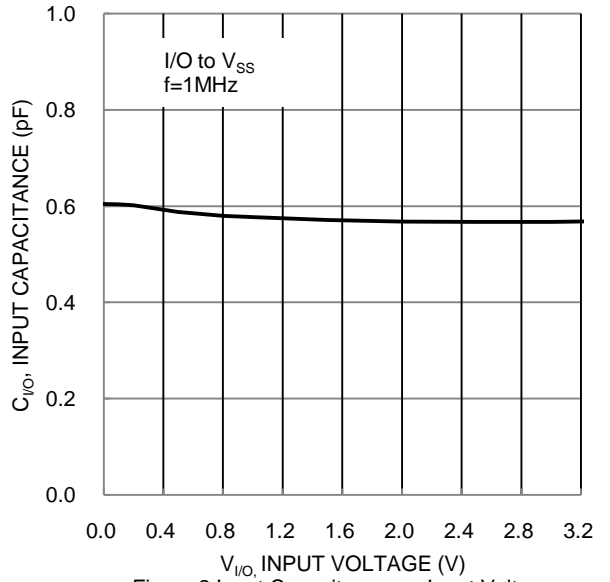


Figure 2 Input Capacitance vs. Input Voltage

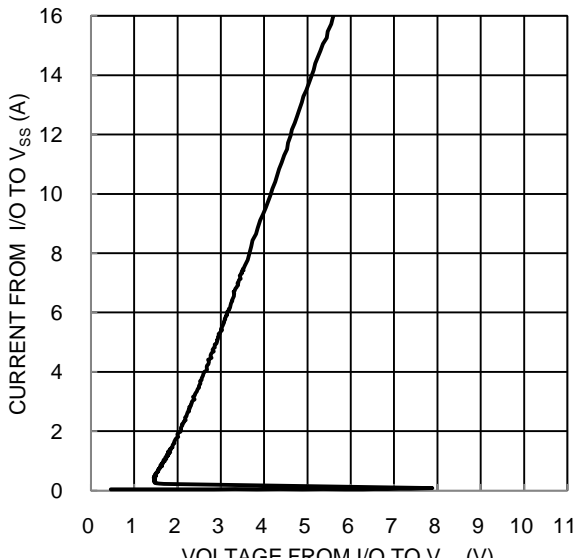
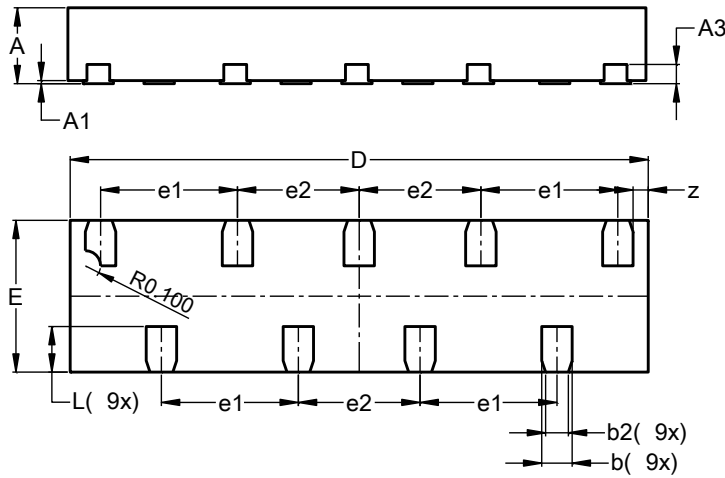


Figure 3 Current vs. Voltage

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**U-DFN3810-9 (Type B)**

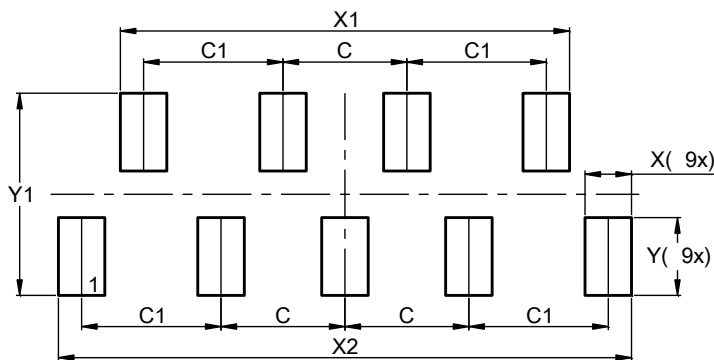


| U-DFN3810-9<br>(Type B) |      |      |       |
|-------------------------|------|------|-------|
| Dim                     | Min  | Max  | Typ   |
| A                       | 0.45 | 0.55 | 0.50  |
| A1                      | 0.00 | 0.05 | 0.02  |
| A3                      | —    | —    | 0.127 |
| b                       | 0.15 | 0.25 | 0.20  |
| b2                      | 0.10 | 0.20 | 0.15  |
| D                       | 3.75 | 3.85 | 3.80  |
| E                       | 0.95 | 1.05 | 1.00  |
| e1                      | —    | —    | 0.90  |
| e2                      | —    | —    | 0.80  |
| L                       | 0.25 | 0.35 | 0.30  |
| z                       | —    | —    | 0.10  |
| All Dimensions in mm    |      |      |       |

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**U-DFN3810-9 (Type B)**



| Dimensions | Value<br>(in mm) |
|------------|------------------|
| C          | 0.800            |
| C1         | 0.900            |
| X          | 0.300            |
| X1         | 2.900            |
| X2         | 3.700            |
| Y          | 0.500            |
| Y1         | 1.300            |

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